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FAIRCHILD

April 2015

FPF1039
Low On-Resistance, Slew-Rate-Controlled Load Switch

Features

- 1.2 V to 5.5 V Input Voltage Operating Range
- Typical R_{ON}:
  - 20 mΩ at V_{IN}=5.5 V
  - 21 mΩ at V_{IN}=4.5 V
  - 37 mΩ at V_{IN}=1.8 V
  - 75 mΩ at V_{IN}=1.2 V
- Slew Rate / Inrush Control with t_R: 2.7 ms (Typical)
- 3.5 A Maximum Continuous Current Capability
- Output Capacitor Discharge Function
- Low <1 µA Shutdown Current
- ESD Protected: Above 8 kV HBM, 1.5 kV CDM
- GPIO / CMOS-Compatible Enable Circuitry

Applications

- HDD, Storage, and Solid-State Memory Devices
- Portable Media Devices, UMPC, Tablets, MIDs
- Wireless LAN Cards and Modules
- SLR Digital Cameras
- Portable Medical Devices
- GPS and Navigation Equipment
- Industrial Handheld and Enterprise Equipment

Description

The FPF1039 advanced load-management switch target applications requiring a highly integrated solution for disconnecting loads powered from DC power rail (<6 V) with stringent shutdown current targets and high load capacitances (up to 200 µF). The FPF1039 consists of slew-rate controlled low-impedance MOSFET switch (21 mΩ typical) and other integrated analog features. The slew-rate controlled turn-on characteristic prevents inrush current and the resulting excessive voltage droop on power rails.

This device has exceptionally low shutdown current drain (<1 µA maximum) that facilitates compliance in low standby power applications. The input voltage range operates from 1.2 V to 5.5 V DC to support a wide range of applications in consumer, optical, medical, storage, portable, and industrial device power management.

Switch control is managed by a logic input (active HIGH) capable of interfacing directly with low-voltage control signal / GPIO with no external pull-up required. The device is packaged in advanced fully “green” 1mm x1.5 mm Wafer-Level Chip-Scale Packaging (WLCSP); providing excellent thermal conductivity, small footprint, and low electrical resistance for wider application usage.

Ordering Information

Part Number	Top Mark	Switch R_{ON} (Typical) at 4.5 V_{IN}	Input Buffer	Output Discharge	ON Pin Activity	t_R	Package
FPF1039UCX	QF	21 mΩ	CMOS	65Ω	Active HIGH	2.7 ms	6-Bump, WLCSP, 1.0 mm x 1.5 mm, 0.5 mm Pitch
FPF1039BUCX	QF	21 mΩ	CMOS	65Ω	Active HIGH	2.7 ms	6-Bump, WLCSP with Backside Laminate, 1.0 mm x 1.5 mm, 0.5 mm Pitch

Application Diagram

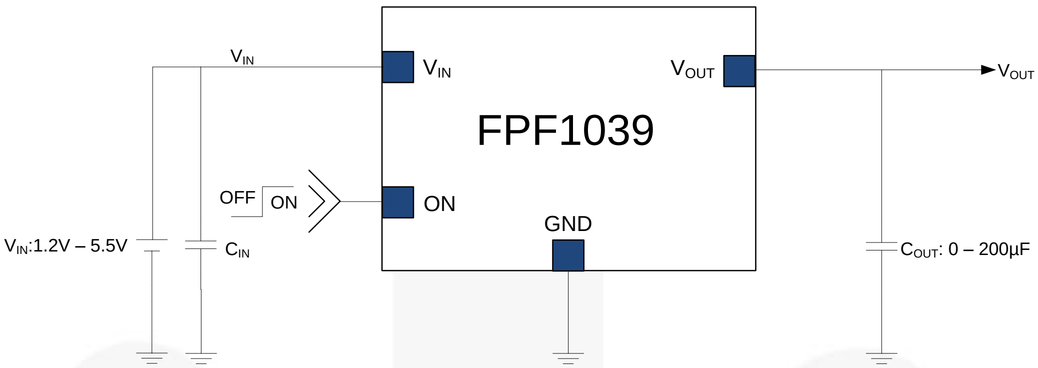


Figure 1. Typical Application

Functional Block Diagram

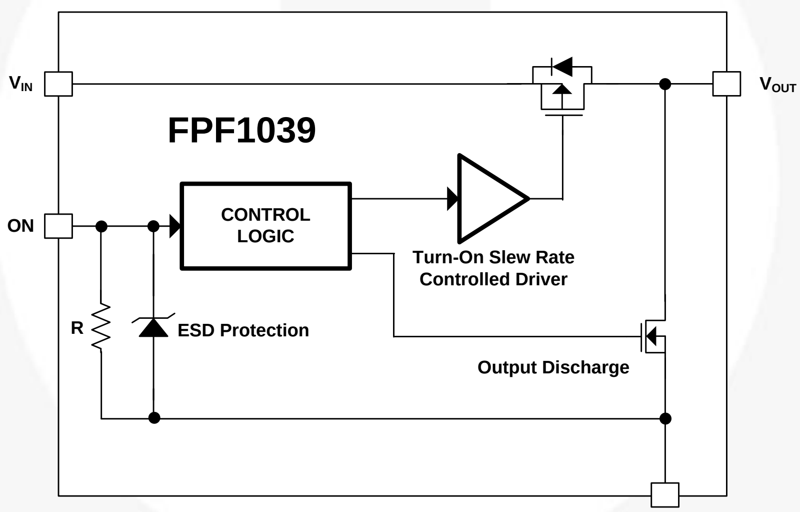


Figure 2. Functional Block Diagram

Pin Configuration

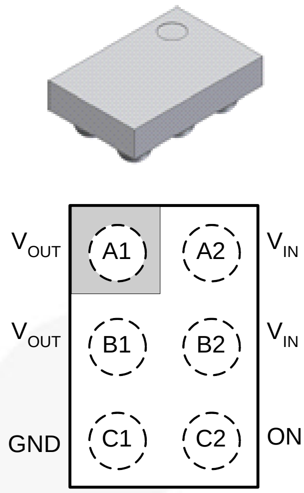


Figure 3. Top View

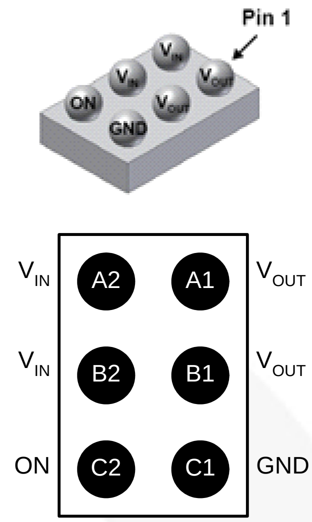


Figure 4. Bottom View

Pin Definitions

Pin #	Name	Description
A1, B1	V_{OUT}	Switch Output
A2, B2	V_{IN}	Supply Input: Input to the Power Switch
C1	GND	Ground
C2	ON	ON/OFF Control, Active High - GPIO Compatible

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameters		Min.	Max.	Unit
V_{IN}	V_{IN}, V_{OUT}, V_{ON} to GND		-0.3	6.0	V
I_{SW}	Maximum Continuous Switch Current			3.5	A
P_D	Power Dissipation at T_A=25°C			1.2	W
T_{STG}	Storage Junction Temperature		-65	+150	°C
T_A	Operating Temperature Range		-40	+85	°C
Θ_{JA}	Thermal Resistance, Junction-to-Ambient			85[1]	°C/W
				110[2]	
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	8.0		kV
		Charged Device Model, JESD22-C101	1.5		

Notes:
1. Measured using 2S2P JEDEC std. PCB.
2. Measured using 2S2P JEDEC PCB COLD PLATE method.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameters	Min.	Max.	Unit
V_{IN}	Input Voltage	1.2	5.5	V
T_A	Ambient Operating Temperature	-40	+85	°C

Electrical Characteristics

Unless otherwise noted, V_{IN}=1.2 to 5.5V and T_A=-40 to +85°C; typical values are at V_{IN}=4.5V and T_A=25°C.

Symbol	Parameters	Conditions	Min.	Typ.	Max.	Units
Basic Operation						
V_{IN}	Input Voltage		1.2		5.5	V
$I_{Q(OFF)}$	Off Supply Current	V_{ON}=GND, V_{OUT}=Open			1.0	µA
I_{SD}	Shutdown Current	V_{ON}=GND, V_{OUT}=GND		0.2	1.0	µA
I_Q	Quiescent Current	I_{OUT}=0 mA		5.5	8.0	µA
R_{ON}	On Resistance	V_{IN}=5.5 V, I_{OUT}=1 A(3)		20	24	mΩ
		V_{IN}=4.5 V, I_{OUT}=1 A, T_A=25°C		21	25	
		V_{IN}=3.3 V, I_{OUT}=500 mA(3)		24	29	
		V_{IN}=2.5 V, I_{OUT}=500 mA(3)		28	35	
		V_{IN}=1.8 V, I_{OUT}=250 mA(3)		37	45	
		V_{IN}=1.2 V, I_{OUT}=250 mA, T_A=25°C		75	100	
R_{PD}	Output Discharge $R_{PULL\ DOWN}$	V_{IN}=4.5 V, V_{ON}=0 V, I_{FORCE}=20 mA, T_A=25°C		65	85	Ω
V_{IH}	On Input Logic HIGH Voltage		1.0			V
V_{IL}	On Input Logic LOW Voltage				0.4	V
I_{ON}	On Input Leakage				1.5	µA
Dynamic Characteristics						
t_{DON}	Turn-On Delay(4)	V_{IN}=4.5 V, R_L=5 Ω, C_L=100 µF, T_A=25°C		1.7		ms
t_R	V_{OUT} Rise Time(4)			2.7		ms
t_{ON}	Turn-On Time(6)			4.4		ms
t_{DOFF}	Turn-Off Delay(4,5)	V_{IN}=4.5 V, R_L=150 Ω, C_L=100 µF, T_A=25°C (5)		0.5		ms
t_F	V_{OUT} Fall Time(4,5)			10.0		ms
t_{OFF}	Turn-Off (5,7)			10.5		ms

Notes:
3. This parameter is guaranteed by design and characterization; not production tested.
4. $t_{DON}/t_{DOFF}/t_R/t_F$ are defined in Figure 32.
5. Output discharge enabled during off-state.
6. $t_{ON}=t_R + t_{DON}$
7. $t_{OFF}=t_F + t_{DOFF}$

Typical Characteristics

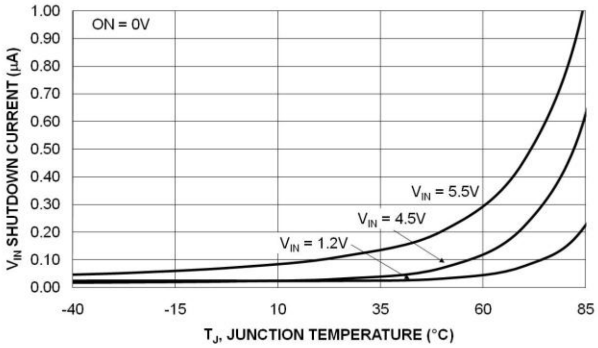


Figure 5. Shutdown Current vs. Temperature

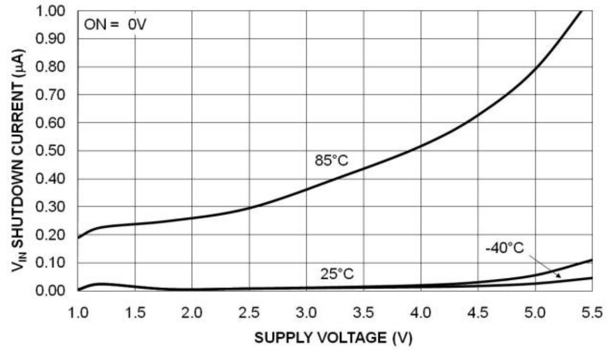


Figure 6. Shutdown Current vs. Supply Voltage

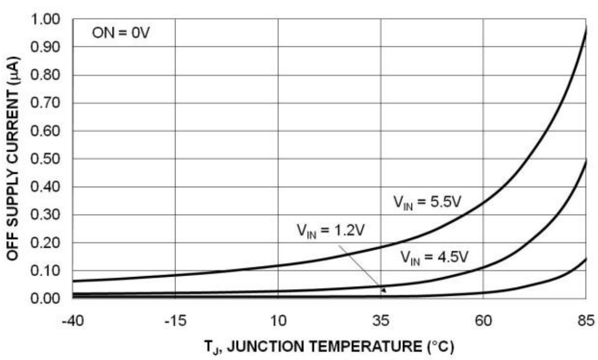


Figure 7. Off Supply Current vs. Temperature (V_{OUT} = 0 V)

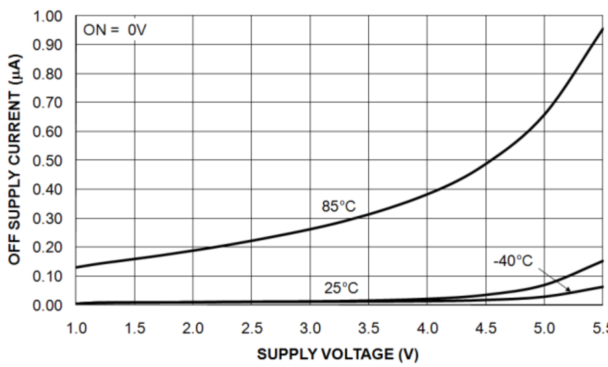


Figure 8. Off Supply Current vs. Supply Voltage (V_{OUT} = 0 V)

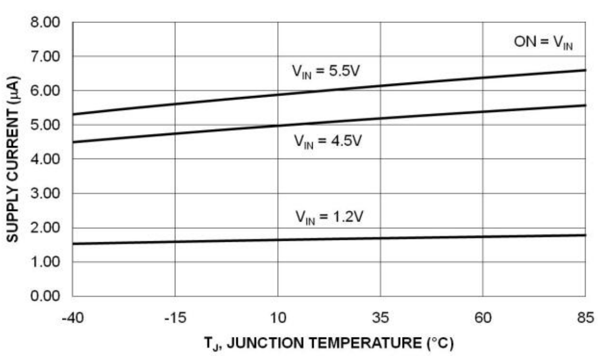


Figure 9. Quiescent Current vs. Temperature

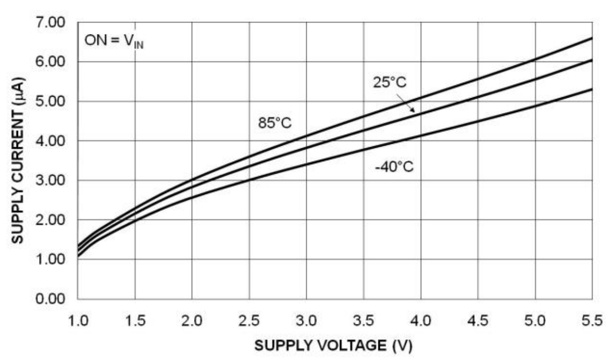


Figure 10. Quiescent Current vs. Supply Voltage

Typical Characteristics (Continued)

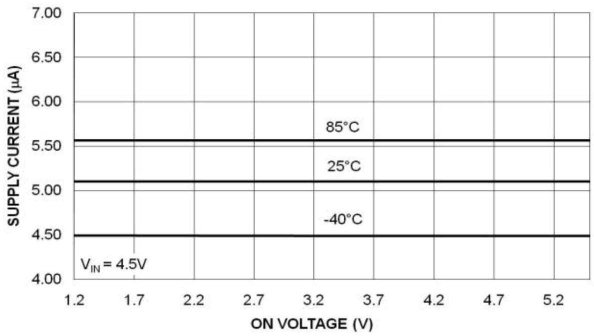


Figure 11. Quiescent Current vs. On Voltage (V_{IN} = 4.5 V)

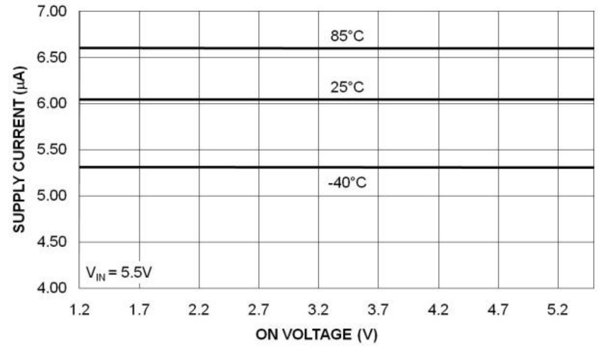


Figure 12. Quiescent Current vs. On Voltage (V_{IN} = 5.5 V)

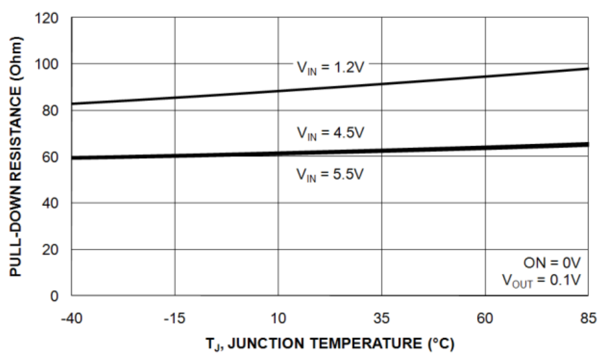


Figure 13. Output Discharge Resistor RPD vs. Temperature

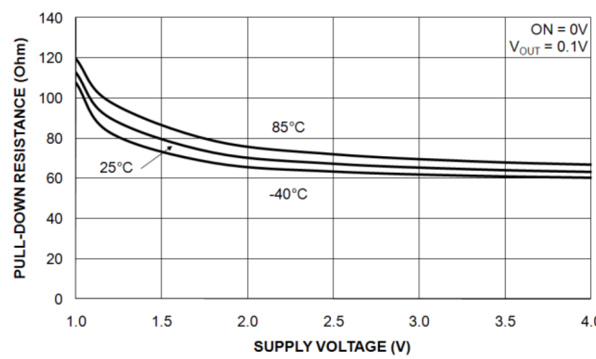


Figure 14. Output Discharge Resistor RPD vs. Supply Voltage

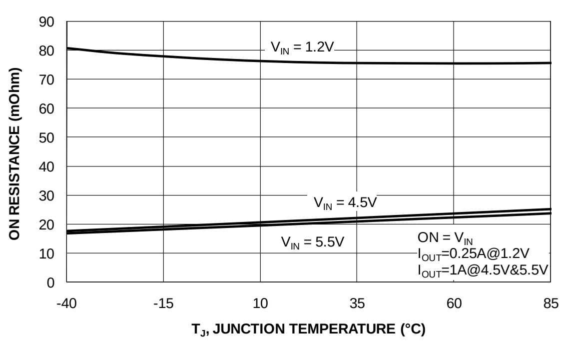


Figure 15. R_{ON} vs. Temperature

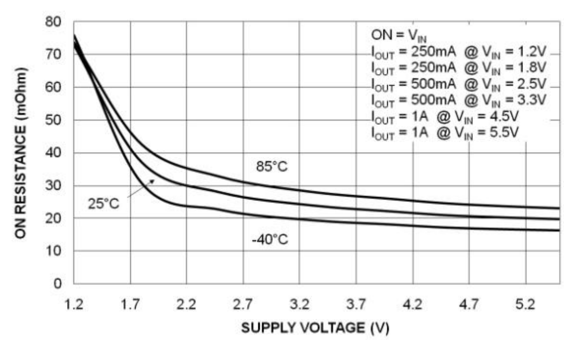


Figure 16. R_{ON} vs. Supply Voltage

Typical Characteristics (Continued)

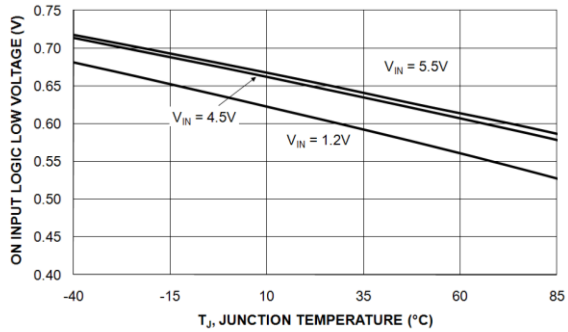


Figure 17. On Pin Threshold Low vs. Temperature

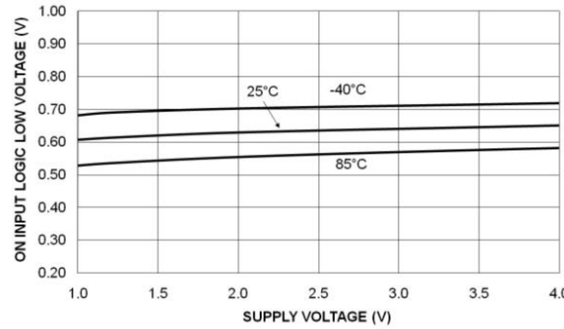


Figure 18. On Pin Threshold Low vs. V_{IN}

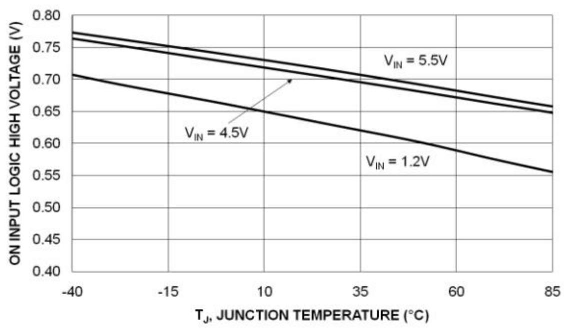


Figure 19. On Pin Threshold High vs. Temperature

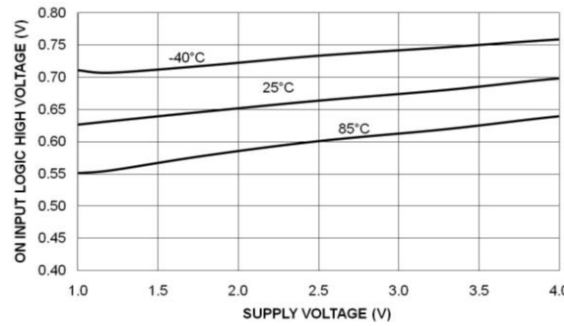


Figure 20. On Pin Threshold High vs. V_{IN}

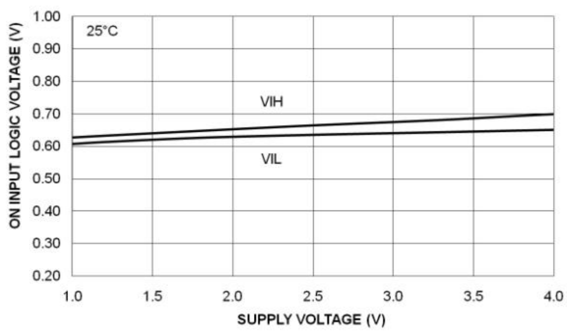


Figure 21. On Pin Threshold vs. Supply Voltage

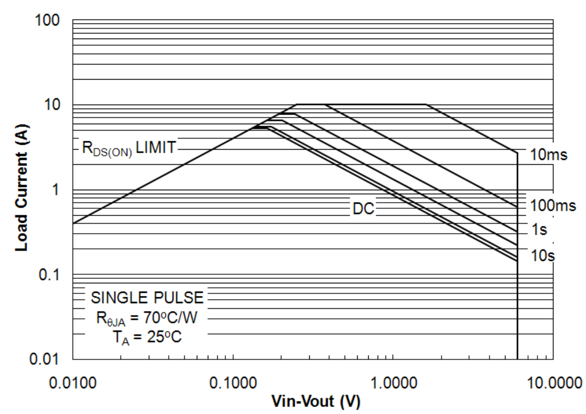


Figure 22. I_{SW} vs. (V_{IN}-V_{OUT}) — SOA

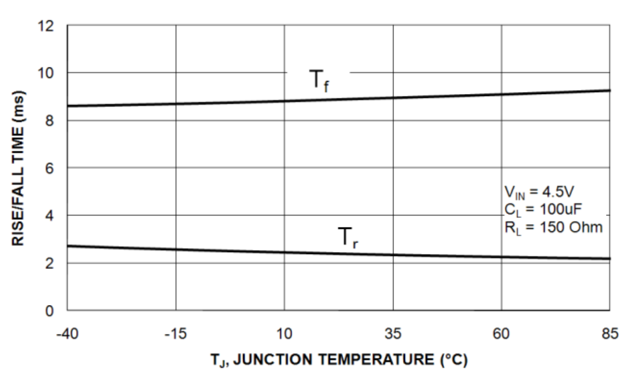


Figure 23. t_R/t_F vs. Temperature

Typical Characteristics (Continued)

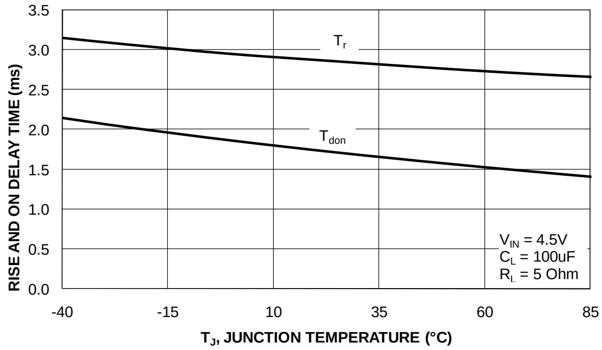


Figure 24. t_R/t_{DON} **vs. Temperature**

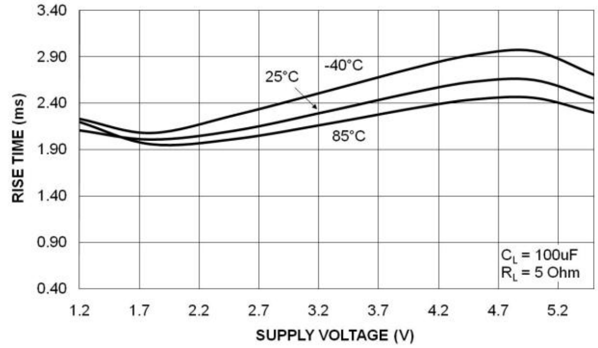


Figure 25. t_R **vs. Supply Voltage**

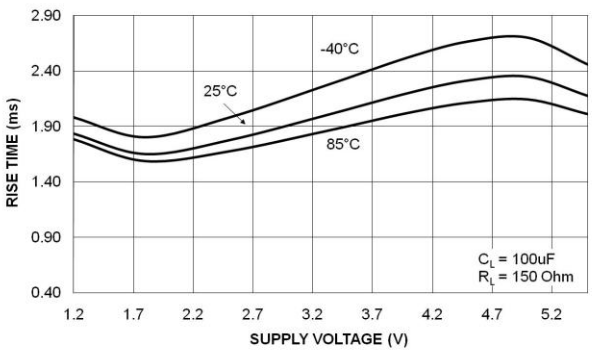


Figure 26. t_R **vs. Supply Voltage**

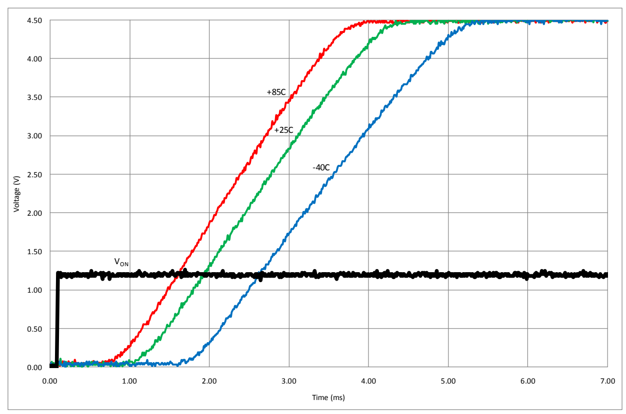


Figure 27. Turn-On Response
(V_{IN}=4.5 V, C_{IN}=10 μF, C_L=1 μF, R_L=50 Ω)

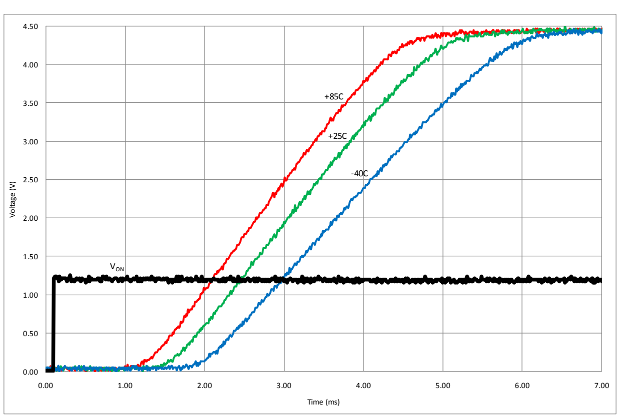


Figure 28. Turn-On Response
(V_{IN}=4.5 V, C_{IN}=10 μF, C_L=100 μF, R_L=5 Ω)

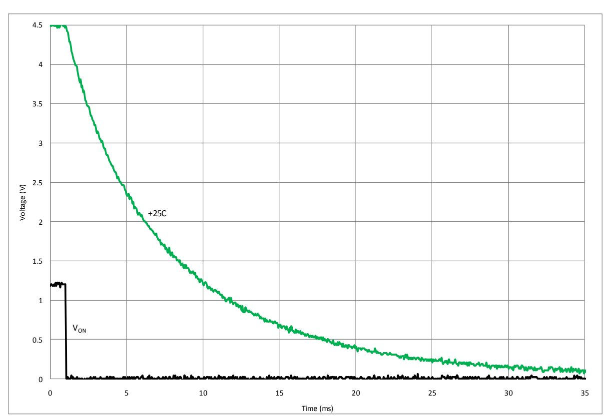


Figure 29. Turn-Off Response
(V_{IN}=4.5 V, C_{IN}=10 μF, C_L=100 μF, without External RL)

Typical Characteristics (Continued)

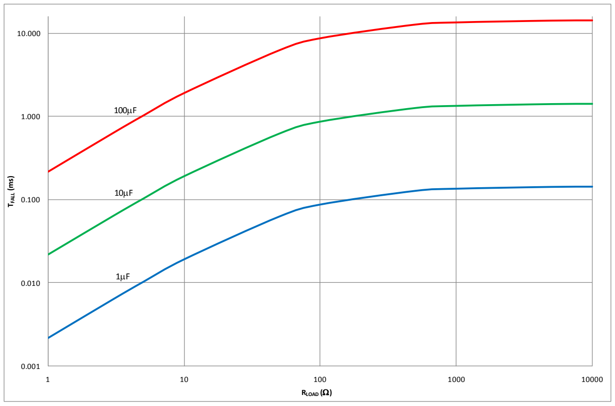


Figure 30. Fall Time as a Function of External Resistive Load (C_L=1 µF, 10 µF, and 100 µF)

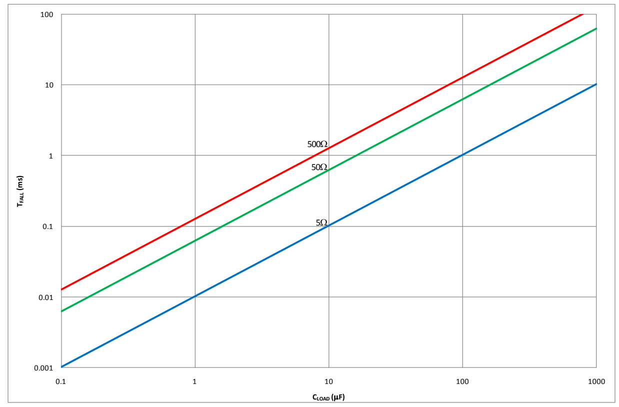


Figure 31. Fall Time as a Function of External Capacitive Load (R_L=5 Ω, 50 Ω, and 500 Ω)

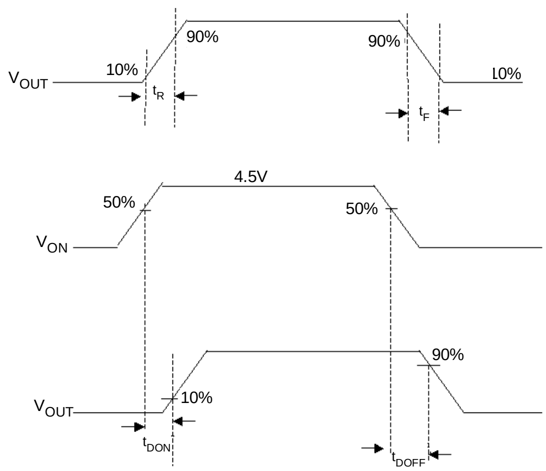


Figure 32. Timing Diagram

Application Information

Input Capacitor

This IntelliMAX™ switch doesn't require an input capacitor. To reduce device inrush current, a 0.1 µF ceramic capacitor, C_{IN}, is recommended close to the VIN pin. A higher value of C_{IN} can be used to reduce the voltage drop experienced as the switch is turned on into a large capacitive load.

Output Capacitor

While this switch works without an output capacitor: if parasitic board inductance forces V_{OUT} below GND when switching off; a 0.1 µF capacitor, C_{OUT}, should be placed between V_{OUT} and GND.

Fall Time

Device output fall time can be calculated based on RC constant of the external components as follows:

$$t_F = R_L \times C_L \times 2.2 \quad (1)$$

where t_F is 90% to 10% fall time, R_L is output load, and C_L is output capacitor.

The same equation works for a device with a pull-down output resistor. R_L is replaced by a parallel connected pull-down and an external output resistor combination as:

$$t_F = \frac{R_L \times R_{PD}}{R_L + R_{PD}} \times C_L \times 2.2 \quad (2)$$

where t_F is 90% to 10% fall time, R_L is output load, R_{PD}=65 Ω is output pull-down resistor, and C_L is the output capacitor.

Resistive Output Load

If resistive output load is missing, the IntelliMAX switch without a pull-down output resistor does not discharge the output voltage. Output voltage drop depends, in that case, mainly on external device leaks.

Application Specifics

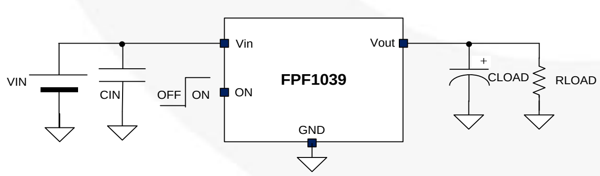


Figure 33. Device Setup

At maximum operational voltage (V_{IN}=5.5 V), device inrush current might be higher than expected. Spike current should be taken into account if V_{IN}>5 V and the output capacitor is much larger than the input capacitor. Input current can be calculated as:

$$I_{IN}(t) \approx \frac{V_{OUT}(t)}{R_{LOAD}} + (C_{LOAD} - C_{IN}) \frac{dV_{OUT}(t)}{dt} \quad (3)$$

where switch and wire resistances are neglected and capacitors are assumed ideal.

Estimating $V_{OUT}(t)=V_{IN}/10$ and using experimental formula for slew rate ($dV_{OUT}(t)/dt$), spike current can be written as:

$$\max(I_{IN}) = \frac{V_{IN}}{10R_{LOAD}} + (C_{LOAD} - C_{IN})(0.05V_{IN} - 0.255) \quad (4)$$

where supply voltage V_{IN} is in volts, capacitances are in micro farads, and resistance is in ohms.

Example: If V_{IN}=5.5V, C_{LOAD}=100 µF, C_{IN}=10 µF, and R_{LOAD}=50 Ω; calculate the spike current by:

$$\max(I_{IN}) = \frac{5.5}{10^*50} + (100 - 10)(0.05^*5.5 - 0.255)A = 1.8A \quad (5)$$

Maximum spike current is 1.8 A, while average ramp-up current is:

$$I_{IN}(t) \approx \frac{V_{OUT}(t)}{R_{LOAD}} + (C_{LOAD} - C_{IN}) \frac{dV_{IN}(t)}{dt} \quad (6)$$

$$\approx 2.75/50 + 100^*0.0022 = 0.275\,A$$

Output Discharge

FPF1039 contains a 65 Ω on-chip pull-down resistor for quick output discharge. The resistor is activated when the switch is turned off.

Recommended Layout

For best thermal performance and minimal inductance and parasitic effects, it is recommended to keep input and output traces short and capacitors as close to the device as possible. Figure 34 is a recommended layout for this device to achieve optimum performance.

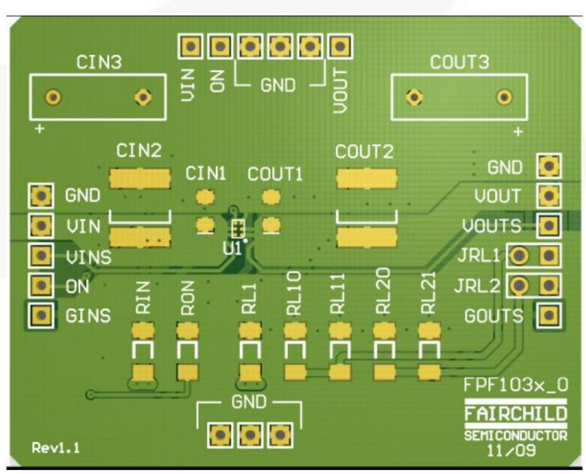
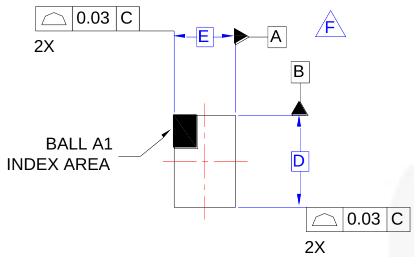
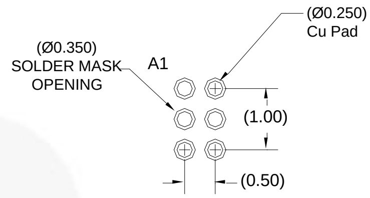


Figure 34. Recommended Land Pattern, Layout

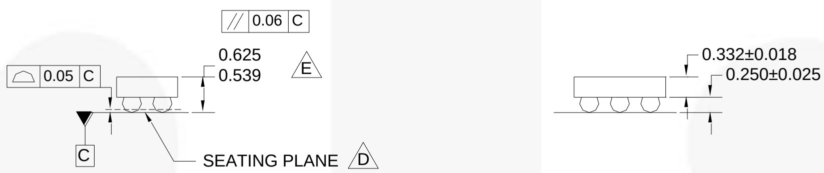
Physical Dimensions



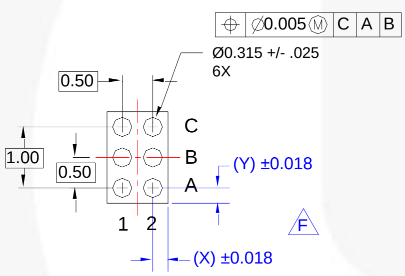
TOP VIEW



RECOMMENDED LAND PATTERN
(NSMD PAD TYPE)



SIDE VIEWS



BOTTOM VIEW

NOTES:

A. NO JEDEC REGISTRATION APPLIES.

B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS AND TOLERANCE PER ASMEY14.5M, 1994.

D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.

E. PACKAGE NOMINAL HEIGHT IS 582 MICRONS ±43 MICRONS (539-625 MICRONS).

F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

G. DRAWING FILNAME: MKT-UC006AFrev2.

Figure 35. 6 Ball, 1.0 x 1.5 mm Wafer-Level Chip-Scale Packaging (WLCSP)

Nominal Values

Bump Pitch	Overall Package Height	Silicon Thickness	Solder Bump Height	Solder Bump Diameter
0.5 mm	0.582 mm	0.332 mm	0.250 mm	0.315 mm

Product-Specific Dimensions

Product	D	E	X	Y
FPF1039UCX	1.46 mm ±0.03	0.96 mm ±0.03	0.230 mm	0.230 mm
FPF1039BUCX	1.46 mm ±0.03	0.96 mm ±0.03	0.230 mm	0.230 mm

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